

## III. Fast / Ultra Fast / Super Fast Recovery Rectifier

### 3.0A Surface Mount Ultra Fast Recovery Rectifier

**US3AB~US3MB**

**(Package: SMB (DO-214AA))**

<p><b>FEATURES</b></p> <ul style="list-style-type: none"> <li>• For surface mounted applications.</li> <li>• Glass passivated junction chip.</li> <li>• Built-in strain relief, ideal for automated placement.</li> <li>• Plastic material used carries Underwriters Laboratory Flammability Classification 94V-0.</li> <li>• Ultra Fast recovery for high efficiency.</li> <li>• High temperature soldering : 260 °C /10 seconds at terminals.</li> </ul> <p><b>MECHANICAL DATA</b></p> <ul style="list-style-type: none"> <li>• Case : Molded plastic</li> <li>• Terminals : Solder plated</li> <li>• Polarity : Indicated by cathode band</li> <li>• Weight : 0.090 grams</li> </ul>	<p>Case: SMB Dimensions in inches and (millimetres)</p>
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## Ratings & Electrical Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20%.

Characteristics	Symbol	US3AB	US3BB	US3DB	US3GB	US3JB	US3KB	US3MB	Units
Maximum recurrent peak reverse voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	Volts
Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	Volts
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	Volts
Maximum average forward rectified current See Fig. 1 @ T <sub>L</sub> =110	I <sub>o</sub>					3.0			Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load. (JEDEC Method)	I <sub>FSM</sub>					100			Amps
Maximum instantaneous forward voltage @ 3.0 A	V <sub>F</sub>		1.0		1.3		1.7		Volts
Maximum DC reverse current @ Ta =25 at rated DC blocking voltage @ Ta =100	I <sub>R</sub>				10.0				µA
					250				
Maximum reverse recovery time (Note 1)	T <sub>rr</sub>		50			75			ns
Typical junction capacitance (Note 2)	C <sub>j</sub>			45					PF
Typical thermal resistance (Note 3)	R <sub>th-JA</sub>			25					/W
Operating temperature range	T <sub>j</sub>			-50 to +150					
Storage temperature range	T <sub>stg</sub>			-50 to +150					

Notes:

1. Reverse recovery test conditions: I<sub>F</sub>=0.5A, I<sub>R</sub>=1.0A, I<sub>RR</sub>=0.25A

2. Measured at 1.0 MHz and applied V<sub>R</sub>=4.0V.

3. Thermal resistance from junction to terminal mounted on 0.6"x0.6" (16x16mm) copper pad areas.

## Ratings and Characteristic Curves of US3AB~US3MB

